DECLARATION OF JOINT INVENTORS FOR PATENT APPLICATION

As the below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: Methods of Forming an Isolation Trench in a Semiconductor, Methods of Forming an Isolation Trench in a Surface of a Silicon Wafer, Methods of Forming an Isolation Trench-Isolated Transistor, Trench-Isolated Transistor, Trench-Isolated Transistor, Trench Isolation Structures Formed in a Semiconductor, Memory Cells and DRAMS, United States Patent Application Serial No. 09/652,550, filed August 31, 2000.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims.

I acknowledge the duty to disclose information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations §1.56.

PRIOR FOREIGN APPLICATIONS:

I hereby state that no applications for foreign patents or inventor's certificates have been filed prior to the date of execution of this declaration.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and

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belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so 2 made are punishable by fine or imprisonment, or both, under 3 Section 1001 of Title 18 of the United States Code and that such willful false statement may jeopardize the validity of the application or any 5 patent issued therefrom. 7 Full name of inventor: KEIJI JONO 8 Inventor's Signature: ___Keiji Jono Date: 10-31-2000 10 Kato-gun, HYOGO Residence: 11 **JAPAN** Citizenship: 12 Post Office Address: 1540-10, Fujita, Yashiro-cho 13 Kato-gun, HYOGO 673-1431 JAPAN 14 15 Full name of inventor: HIROKAZU UEDA 16 Inventor's Signature: Hirokazu Ueda 17 Date: 10-31-00 18 Kobe, HYOGO Residence: 19 **JAPAN** Citizenship: 20 5-2-11, Kumauchi-cho, chuuou-ku

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Full name of inventor: HIROYUKI WATANABE Inventor's Signature: Hiroyuki Watanabe Date: 10-31-2000 Nishiwaki, HYOGO Residence: 5 Citizenship: **JAPAN** 6 1380 KMT No. 2 Nishiwaki-dorm 118, Post Office Address: Nomura-cho Nishiwaki, HYOGO 677-0054 JAPAN 8 10 11 12 13 14 15 16 17